

/ Descriptions

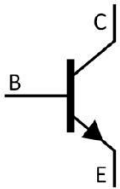
JF K\$*) * E GE Silicon NPN transistor in a SOT-323 Plastic Package.

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Complementary pair with 8550W.

Power amplifier applications.

/ Equivalent Circuit



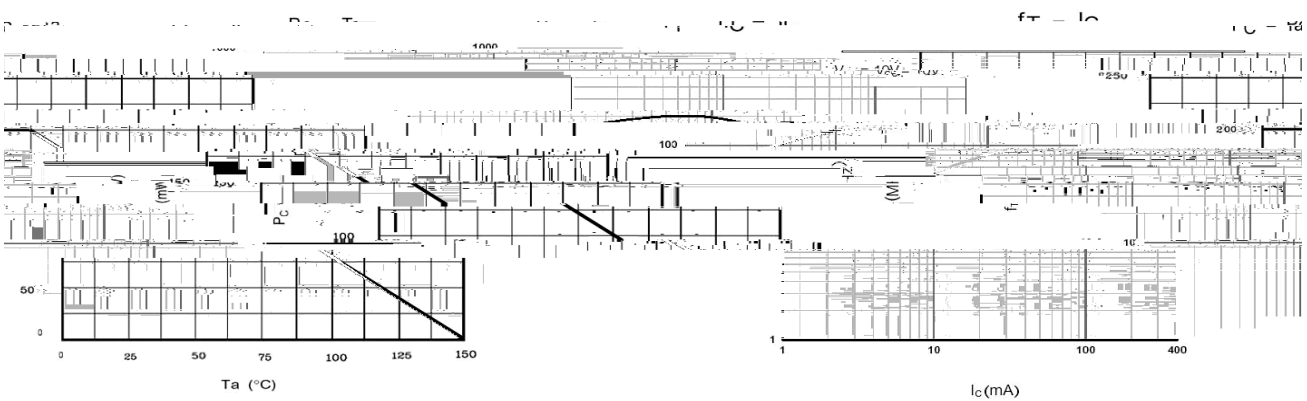
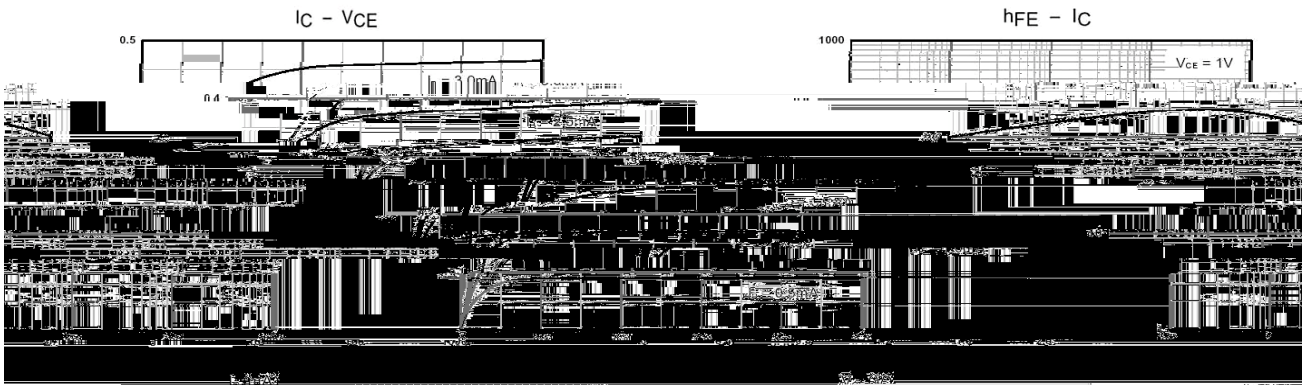
PIN1 Emitter PIN 2 Base PIN 3 Collector

/ Marking

h_{FE} Classifications Symbol	B	C	D
h_{FE} Range	85 160	120 200	160 300
Marking	HY1B	HY1C	HY1D

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	40	V
Collector to Emitter Voltage	V_{CEO}	25	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	1.5	A
Base Current	I_B		

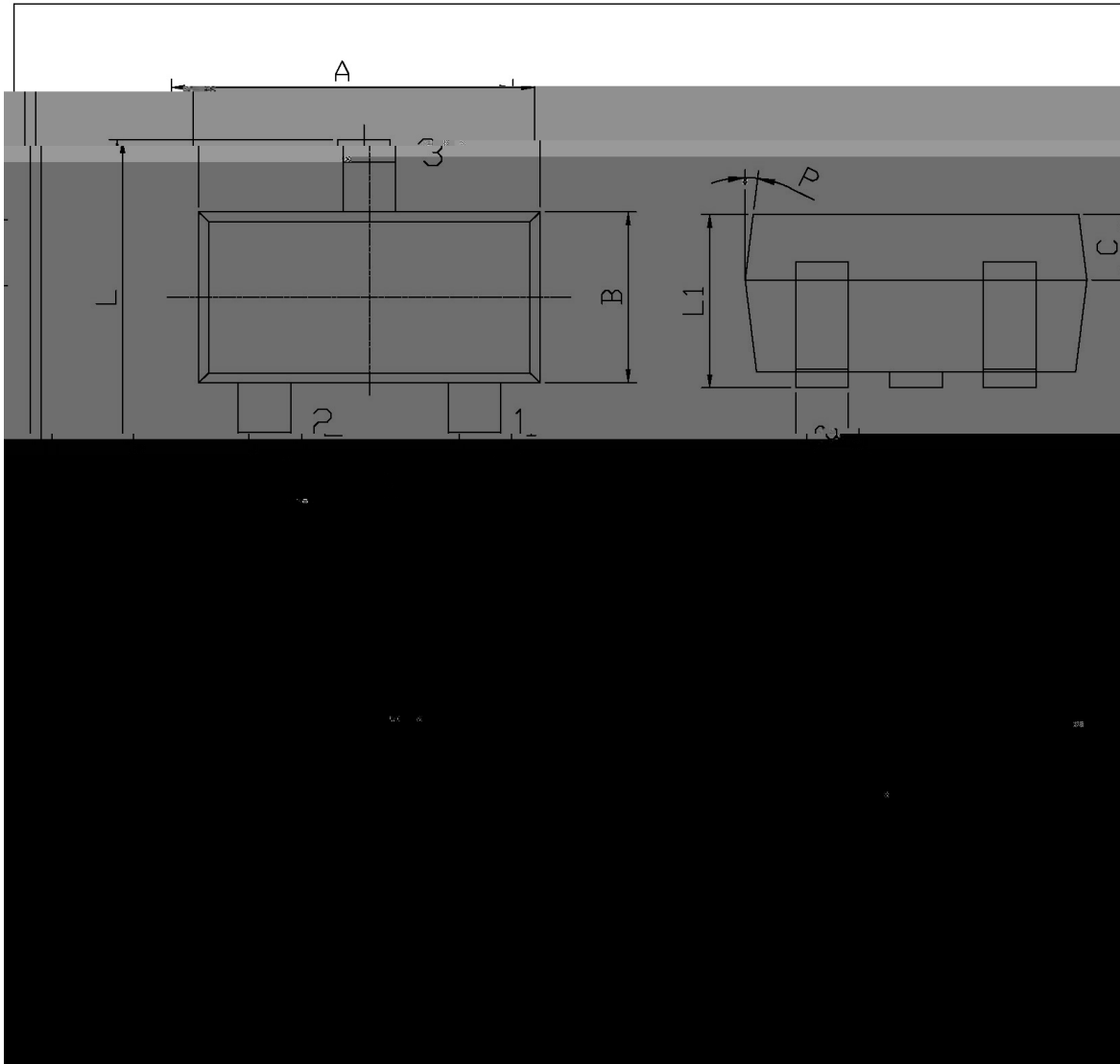
/ Electrical Characteristic Curve



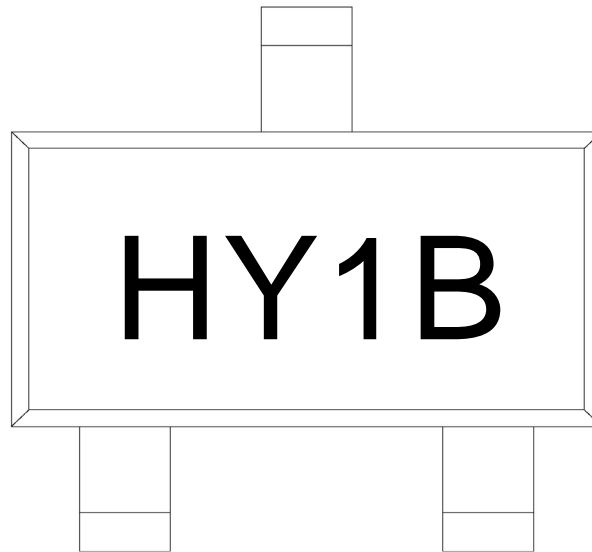
/ Package Dimensions

SOT-323

单位: mm



/ Marking Instructions

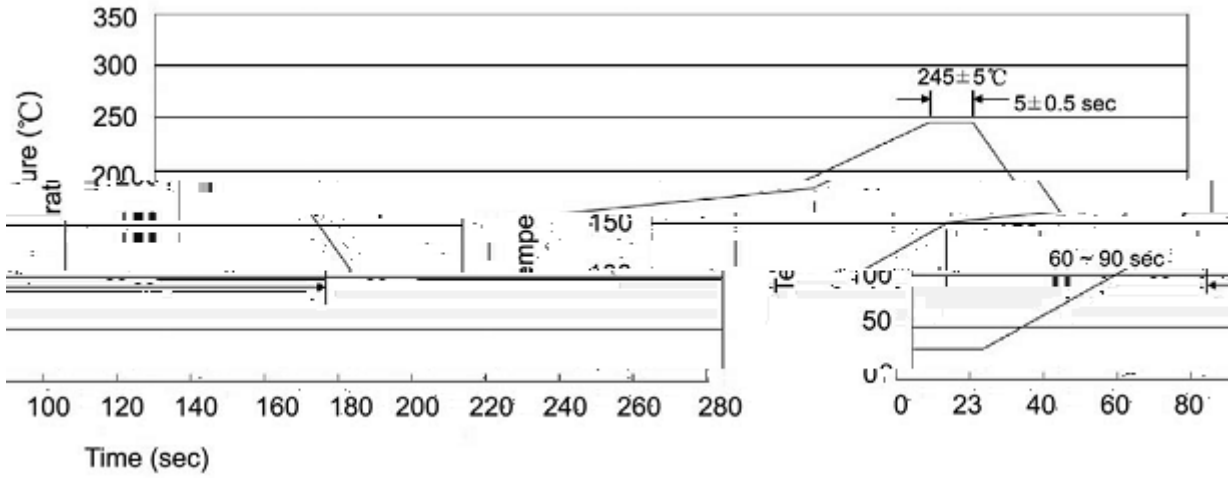


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Note:

- H: Company Code.
- Y1: Product Type.
- B h_{FE} Classifications Symbol

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Note:

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|---|--------|-----|------------|--------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245..5 | | 5..0.5sec; | | 2.Peak Temp.:245..5 , Duration:5..0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

260..5 10..1 sec. Temp.:260±5 Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量	Dimension 包装尺寸 (unit: mm ³)
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